NSN 5961-01-307-7630

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-307-7630 **Inclosure Material:** Metal **Overall Length:** 1.406 inches **Overall Diameter:** 1.120 inches **Mounting Facility Quantity: Mounting Method:** Threaded hole **Features Provided:** Hermetically sealed case **Thread Size:** 0.312 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 working peak reverse voltage and 50.0 reverse voltage, instantaneous **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius case **Thread Series Designator:** Unc **Terminal Type And Quantity:** 1 threaded hole and 1 threaded stud Shelf Life: N/a **Unit Of Measure:** Demilitarization: No

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